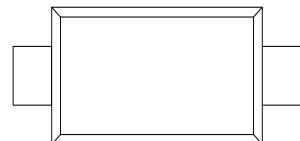


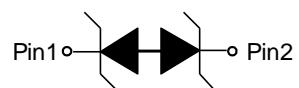
Product Summary

The GESDBS24VD1F1P is designed to protect voltage sensitive electronic components from ESD and other transients. Excellent clamping capability, low leakage, low capacitance, and fast response time, make these parts ideal for ESD protection on designs where board space is at a premium. Because of its small size, it is suited for use in digital cameras, cellular phones, MP3 players and many other portable applications where board space is at a premium. It has been specifically designed to protect sensitive components which are connected to data and transmission lines from overvoltage caused by ESD(electrostatic discharge), and EFT (electrical fast transients).

SOD-123FL



Schematic diagram



Feature

- Low reverse stand-off voltage: 24V
- Low leakage current
- 7500W Peak pulse power per line ($t_p = 8/20\mu s$)
- SOD-123FL package
- Response time is typically < 1ns
- Protect one I/O or power line

Application

- Cell phone handsets and accessories
- Personal digital assistants (PDA's)
- Notebooks, desktops and servers
- Portable instrumentation
- Cordless phones
- Digital cameras
- Peripherals
- MP3 players
- Digital cameras

Marking: 24C

Absolute Maximum Ratings ($T_a=25^\circ\text{C}$ unless otherwise noted)

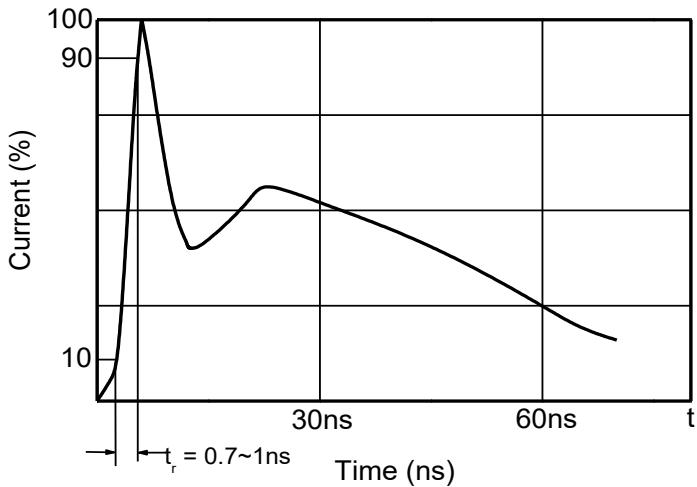
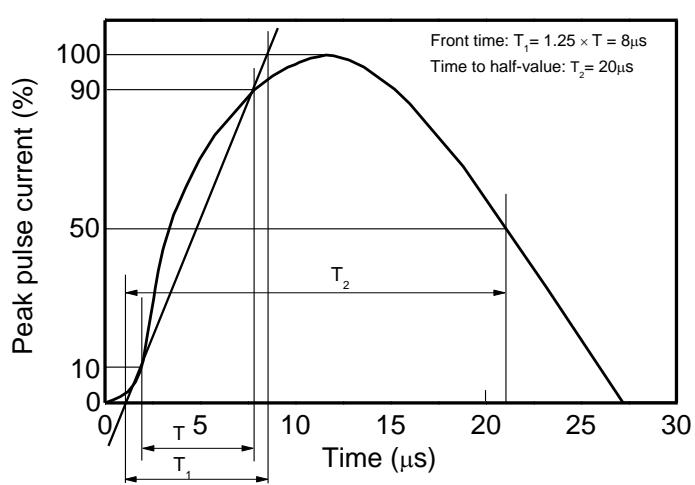
Parameter	Symbol	Value	Unit
IEC 61000-4-2 ESD Voltage	V_{ESD}	± 30	KV
IEC 61000-4-2 ESD Voltage		± 30	
ESD Voltage		± 16	
ESD Voltage		± 0.4	
Peak Pulse Power	P_{PP}	7500	W
Peak Pulse Current	I_{PP}	250	A
Lead Solder Temperature – Maximum (10 Second Duration)	T_L	260	$^\circ\text{C}$
Junction Temperature	T_j	150	$^\circ\text{C}$
Storage Temperature	T_{stg}	-55~+150	$^\circ\text{C}$

ESD standards compliance
IEC61000-4-2 Standard

Contact Discharge		Air Discharge	
Level	Test Voltage kV	Level	Test Voltage kV
1	2	1	2
2	4	2	4
3	6	3	8
4	8	4	15

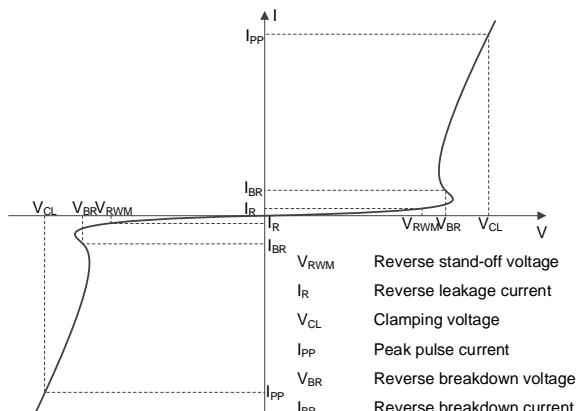
JESD22-A114-B Standard

ESD Class	Human Body Discharge V
0	0~249
1A	250~499
1B	500~999
1C	1000~1999
2	2000~3999
3A	4000~7999
3B	8000~15999

Contact discharge current waveform per IEC61000-4-2

8/20μs waveform per IEC61000-4-5


Electrical Parameter

Symbol	Parameter
V _C	Clamping Voltage @ I _{PP}
I _{PP}	Peak Pulse Current
V _{BR}	Breakdown Voltage @ I _{BR}
I _{BR}	Test Current
I _R	Reverse Leakage Current @ V _{RWM}
V _{RWM}	Reverse Standoff Voltage

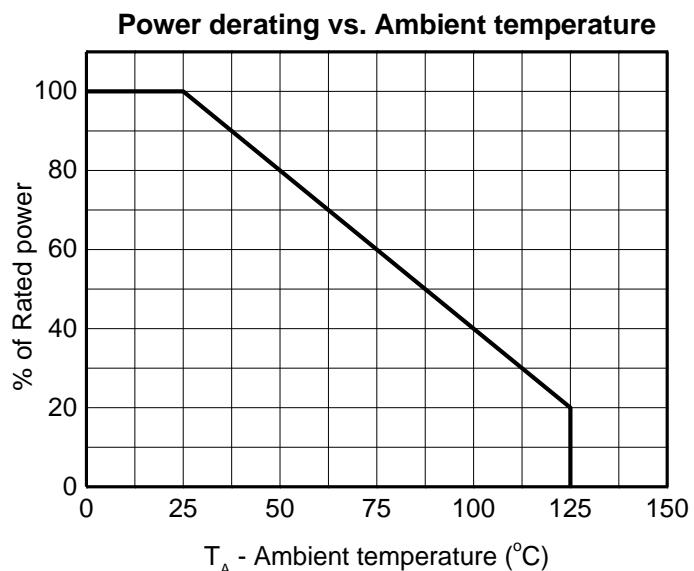
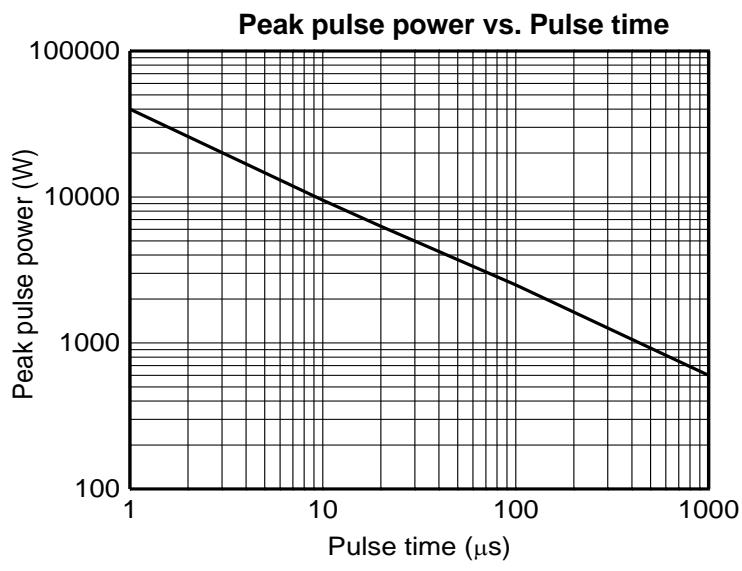
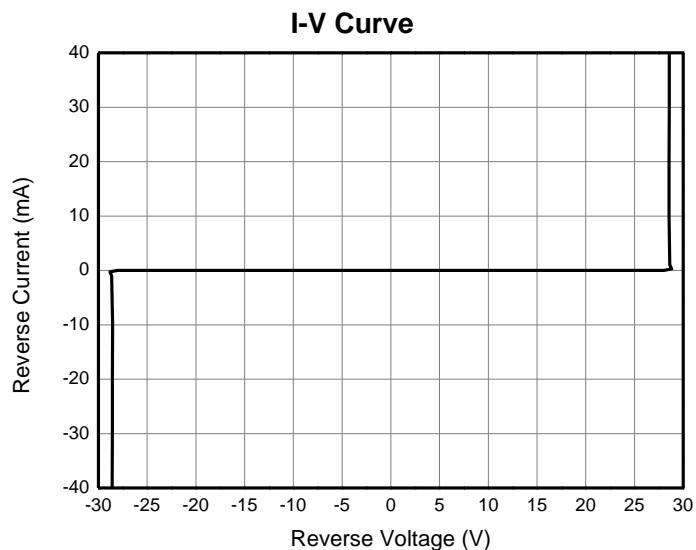
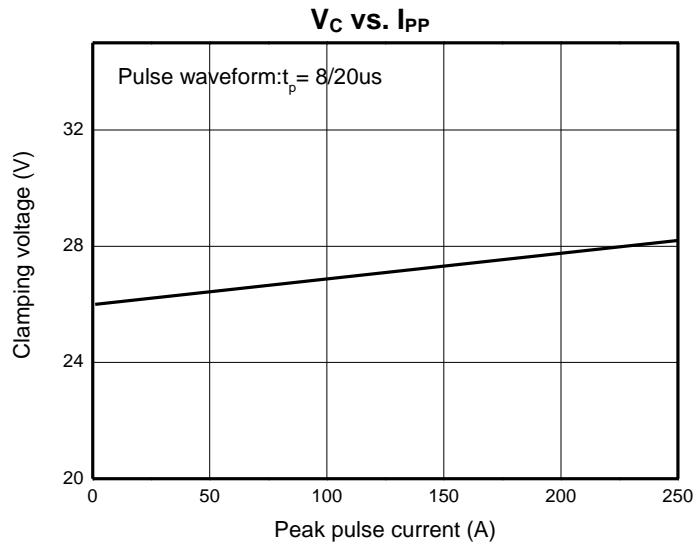


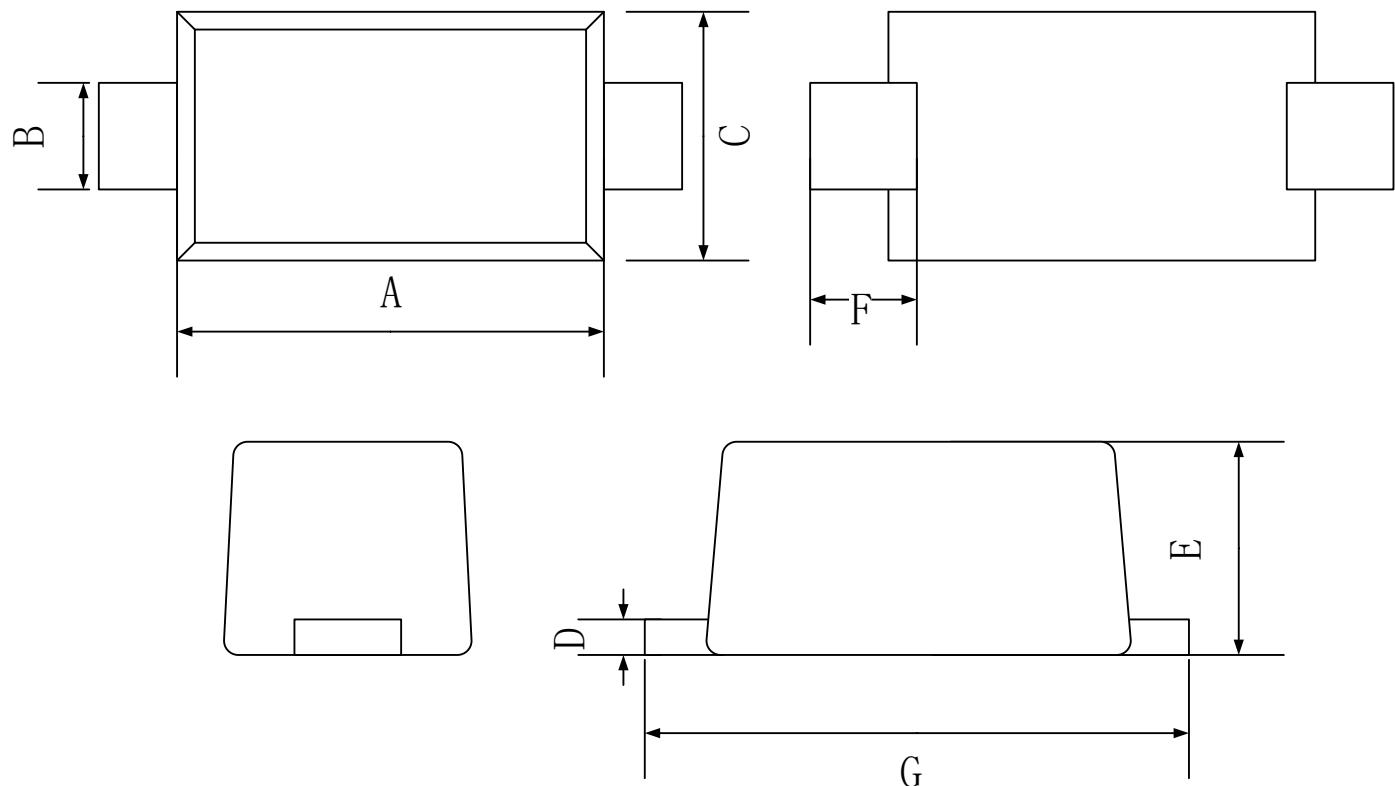
V-I characteristics for a Bi-directional TVS

Electrical Characteristics (Ta=25°C unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Reverse stand-off voltage	V _{RWM}				24	V
Reverse leakage current	I _R	V _{RWM} =24V			5	µA
Breakdown voltage	V _{BR} ¹⁾	I _T =1mA	26.1		30	V
Clamping voltage	V _{C1}	I _{PP} =250A(8/20µS)		28	31	V
Junction capacitance	C _j	V _R =0V,f=1MHz		300		pF

1) V_{BR} is measured with a pulse test current IT at an ambient temperature of 25°C

Typical Characteristics


SOD-123FL Package Outline Dimensions


Symbol	Dimensions In Millimeters	
	Min.	Max.
A	2.85	2.95
B	0.99	1.01
C	1.75	1.85
D	0.10	0.20
E	0.95	1.05
F	0.65	0.85
G	3.75	4.05